# Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

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# -CHANNEL MOS FIELD EFFECT POWER TRANSISTOR

# Phase-out/Discontinued 2SK736

DESCRIPTION

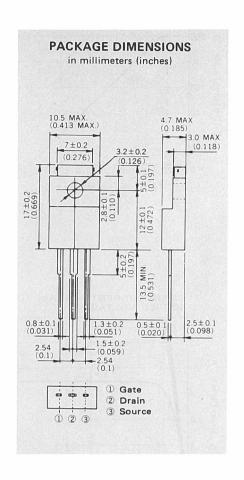
The 2SK736 is N-Channel MOS Field Effect Power Transistor designed for solenoid, motor and lamp driver.

**FEATURES** 

- Gate Drive Logic level -
- Low R<sub>DS(on)</sub>
- No Secondary Breakdown

#### **ABSOLUTE MAXIMUM RATINGS**

Maximum Temperatures						
Storage Temperature						
Channel Temperature 150	°C Max	imum				
Maximum Power Dissipations						
Total Power Dissipation ( $T_a = 25$ °C)	2.0	W				
Total Power Dissipation ( $T_C = 25$ °C)	35	W				
Maximum Voltages and Currents (T <sub>a</sub> = 25 °C)						
V <sub>DSS</sub> Drain to Source Voltage	100	V				
V <sub>GSS</sub> Gate to Source Voltage	±20	V				
I <sub>D(DC)</sub> Drain Current (DC)	±15	Α				
I <sub>D(pulse)</sub> Drain Current (pulse)*	±60	Α				
*PW $\leq$ 300 $\mu$ s, Duty Cycle $\leq$ 10 %						



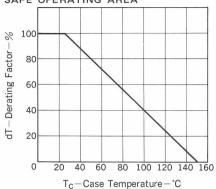
# ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

SYMBOL	CHARACTERISTIC	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
R <sub>DS(on)</sub>	Drain to Source On-State Resistance			80.0	Ω	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 6 A
R <sub>DS(on)</sub>	Drain to Source On-State Resistance			0.10	Ω	$V_{GS} = 4 V, I_D = 6 A$
VGS(off)	Gate to Source Cutoff Voltage	1.0		2.5	V	$V_{DS} = 10 \text{ V, I}_{D} = 1 \text{ mA}$
y <sub>fs</sub>	Forward Transfer Admittance	5.0			S	$V_{DS} = 10 \text{ V, I}_{D} = 6 \text{ A}$
IDSS	Drain Leakage Current			10	μΑ	$V_{DS} = 100 \text{ V}, V_{GS} = 0$
IGSS	Gate to Source Leakage Current			±100	nA	$V_{GS} = \pm 20 \text{ V, } V_{DS} = 0$
C <sub>iss</sub>	Input Capacitance		2400		pF	V <sub>DS</sub> = 10 V
Coss	Output Capacitance		600		pF	V <sub>GS</sub> = 0
C <sub>rss</sub>	Reverse Transfer Capacitance		100		pF	f = 1 MHz
<sup>t</sup> d(on)	Turn On Delay Time		15		ns	
t <sub>r</sub>	Rise Time		70		ns	I <sub>D</sub> = 6 A, V <sub>CC</sub>
<sup>t</sup> d(off)	Turn Off Delay Time		250		ns	$R_{in} = 10 \Omega$
tf	Fall Time		160		ns	

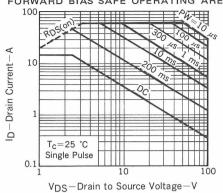


# TYPICAL CHARACTERISTICS (Ta = 25 °C)

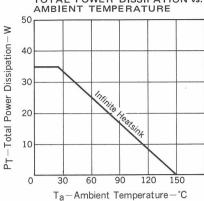
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



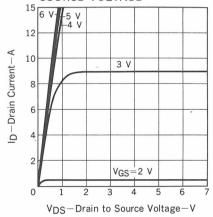
FORWARD BIAS SAFE OPERATING AREA



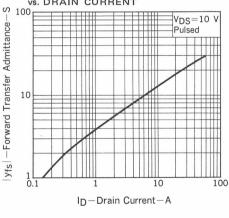
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



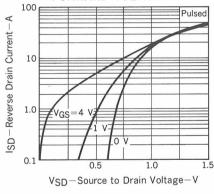
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE

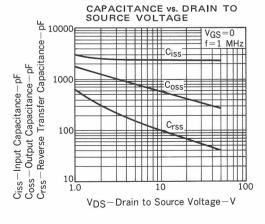


FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT

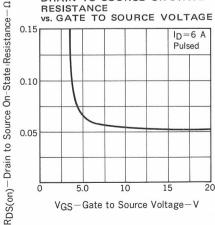


SOURCE TO DRAIN DIODE FORWARD VOLTAGE

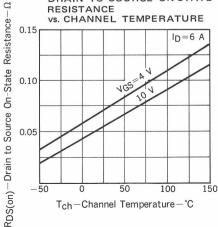


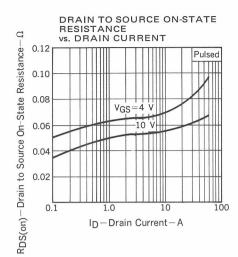


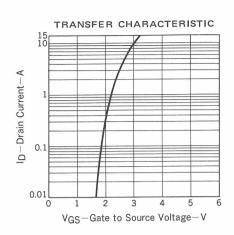
DRAIN TO SOURCE ON-STATE RESISTANCE

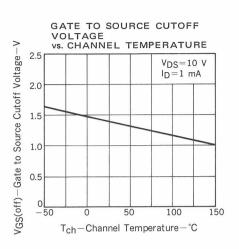


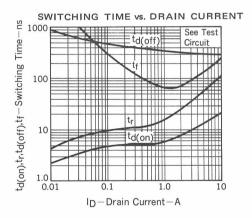
DRAIN TO SOURCE ON-STATE RESISTANCE



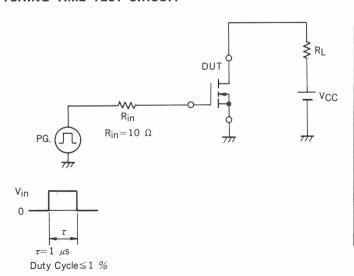


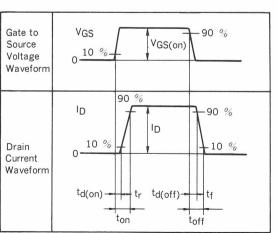






## SWITCHING TIME TEST CIRCUIT





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